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Kind regards,

Team Nexperia



BSH205G2

20 V, P-channel Trench MOSFET

29 April 2015

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Low on-state resistance
- Trench MOSFET technology
- Enhanced power dissipation capability of 890 mW
- AEC-Q101 qualified

3. Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j = 25^\circ\text{C}$		-	-	-20	V
V_{GS}	gate-source voltage			-8	-	8	V
I_D	drain current	$V_{GS} = -4.5\text{ V}$; $T_{amb} = 25^\circ\text{C}$; $t \leq 5\text{ s}$	[1]	-	-	-2.3	A
Static characteristics							
R_{DSon}	drain-source on-state resistance	$V_{GS} = -4.5\text{ V}$; $I_D = -2\text{ A}$; $T_j = 25^\circ\text{C}$		-	120	170	$\text{m}\Omega$

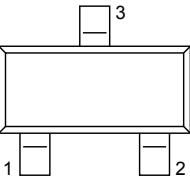
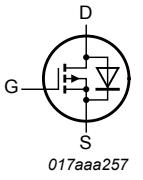
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm^2 .



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	S	source		
3	D	drain	 TO-236AB (SOT23)	

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BSH205G2	TO-236AB	plastic surface-mounted package; 3 leads	SOT23

7. Marking

Table 4. Marking codes

Type number	Marking code
BSH205G2	[1] %KB

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	$T_j = 25^\circ\text{C}$		-	-20	V
V_{GS}	gate-source voltage			-8	8	V
I_D	drain current	$V_{GS} = -4.5\text{ V}$; $T_{amb} = 25^\circ\text{C}$; $t \leq 5\text{ s}$	[1]	-	-2.3	A
		$V_{GS} = -4.5\text{ V}$; $T_{amb} = 25^\circ\text{C}$	[1]	-	-2	A
		$V_{GS} = -4.5\text{ V}$; $T_{amb} = 100^\circ\text{C}$	[1]	-	-1.2	A
I_{DM}	peak drain current	$T_{amb} = 25^\circ\text{C}$; single pulse; $t_p \leq 10\text{ }\mu\text{s}$		-	-8	A
P_{tot}	total power dissipation	$T_{amb} = 25^\circ\text{C}$	[2]	-	480	mW
			[1]	-	890	mW
		$T_{sp} = 25^\circ\text{C}$		-	6250	mW
T_j	junction temperature			-55	150	°C
T_{amb}	ambient temperature			-55	150	°C
T_{stg}	storage temperature			-65	150	°C
Source-drain diode						
I_S	source current	$T_{sp} = 25^\circ\text{C}$	[1]	-	-0.8	A

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

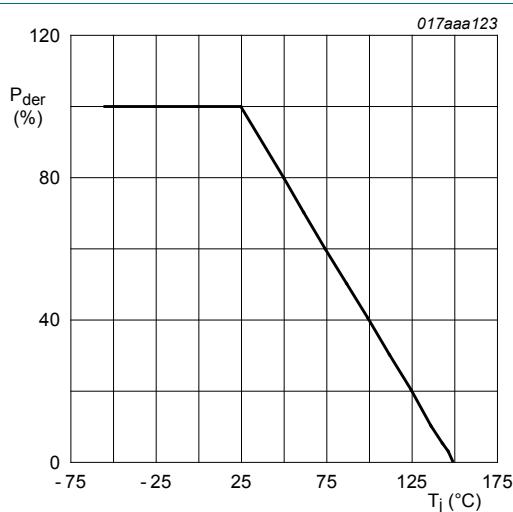


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot}(25^\circ\text{C})} \times 100 \text{ %}$$

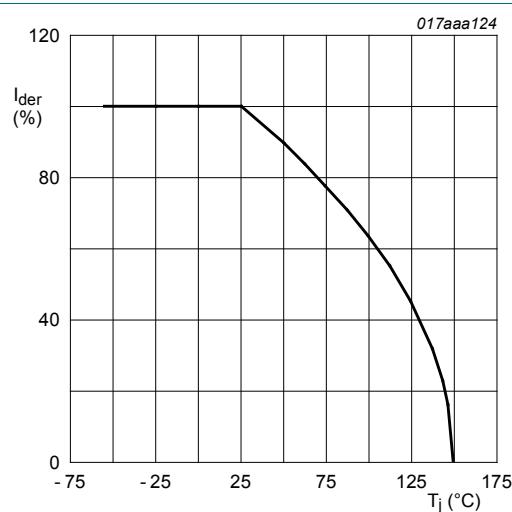
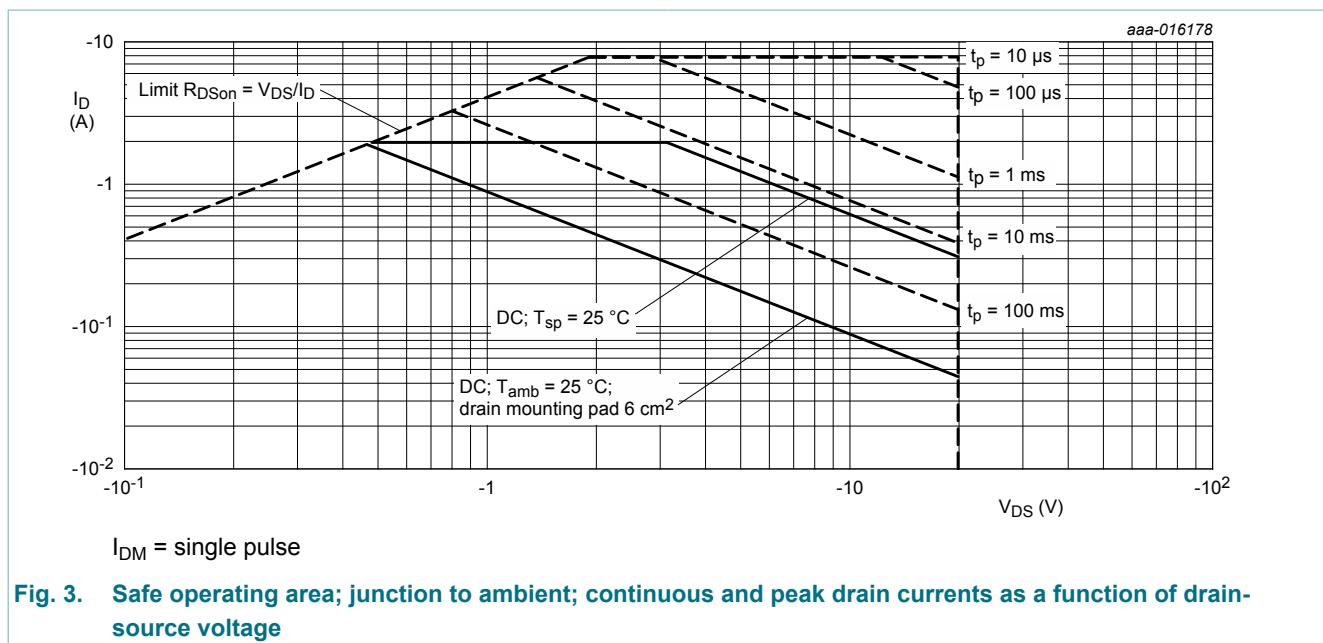


Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_D(25^\circ\text{C})} \times 100 \text{ %}$$



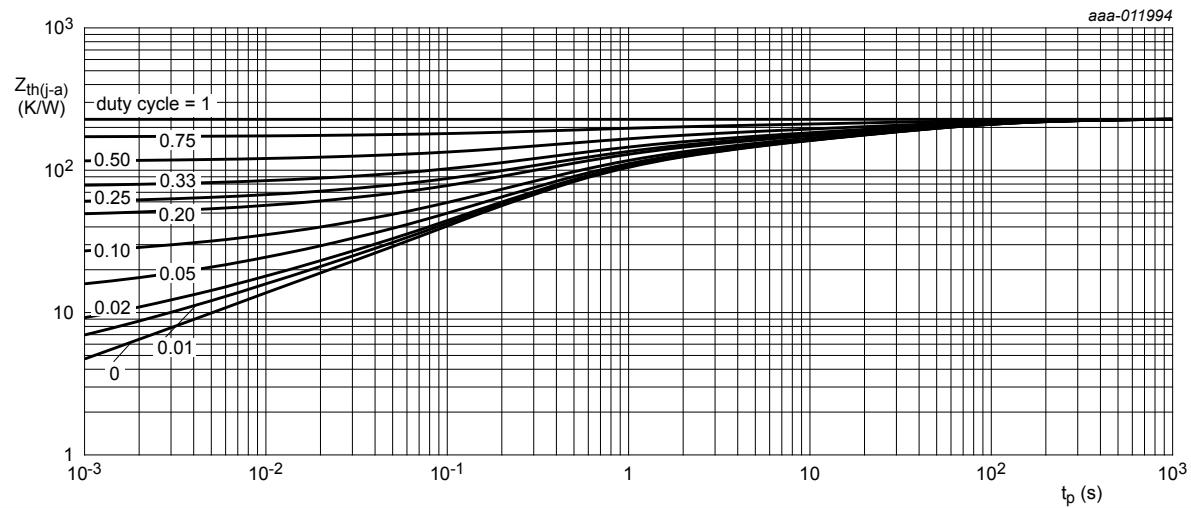
9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	230	260	K/W
			[2]	-	120	140	K/W
		in free air; $t \leq 5 \text{ s}$	[2]	-	85	100	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	15	20	K/W

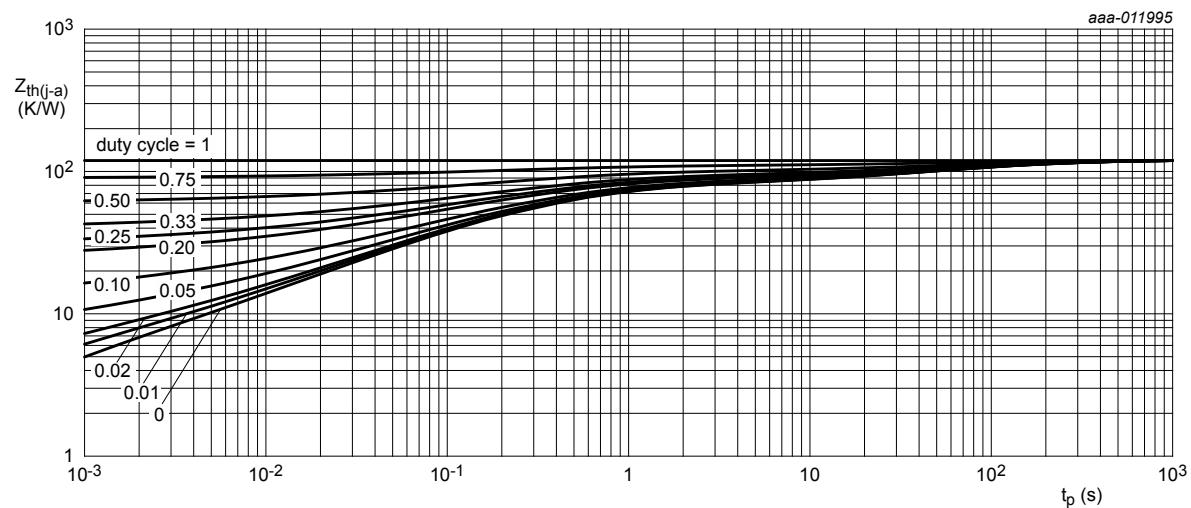
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm^2 .



FR4 PCB, standard footprint

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



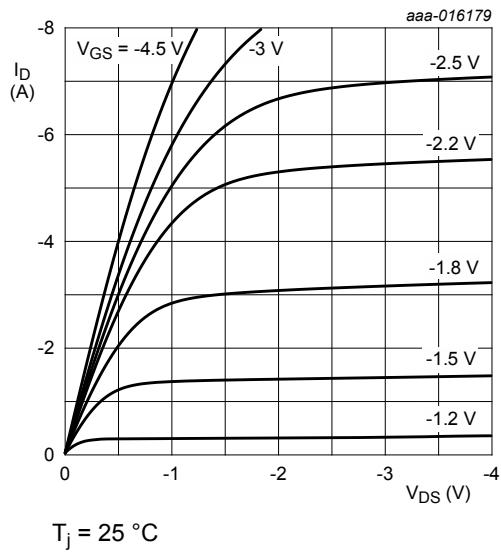
FR4 PCB, mounting pad for drain 6 cm^2

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

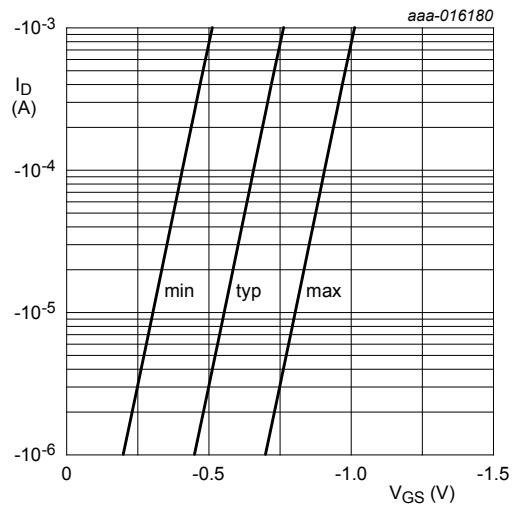
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = -250 \mu A; V_{GS} = 0 V; T_j = 25^\circ C$		-20	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = -250 \mu A; V_{DS} = V_{GS}; T_j = 25^\circ C$		-0.45	-0.7	-0.95	V
I_{DSS}	drain leakage current	$V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25^\circ C$		-	-	-1	μA
I_{GSS}	gate leakage current	$V_{GS} = 8 V; V_{DS} = 0 V; T_j = 25^\circ C$		-	-	100	nA
		$V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25^\circ C$		-	-	-100	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = -4.5 V; I_D = -2 A; T_j = 25^\circ C$		-	120	170	$m\Omega$
		$V_{GS} = -4.5 V; I_D = -2 A; T_j = 150^\circ C$		-	168	238	$m\Omega$
		$V_{GS} = -2.5 V; I_D = -1.5 A; T_j = 25^\circ C$		-	150	230	$m\Omega$
		$V_{GS} = -1.8 V; I_D = -0.6 A; T_j = 25^\circ C$		-	200	320	$m\Omega$
		$V_{GS} = -1.5 V; I_D = -0.1 A; T_j = 25^\circ C$		-	260	600	$m\Omega$
g_{fs}	forward transconductance	$V_{DS} = -10 V; I_D = -2 A; T_j = 25^\circ C$		-	4.5	-	S
Dynamic characteristics							
$Q_{G(tot)}$	total gate charge	$V_{DS} = -10 V; I_D = -2 A; V_{GS} = -4.5 V; T_j = 25^\circ C$		-	3.7	6.5	nC
Q_{GS}	gate-source charge			-	0.6	-	nC
Q_{GD}	gate-drain charge			-	0.8	-	nC
C_{iss}	input capacitance	$V_{DS} = -10 V; f = 1 MHz; V_{GS} = 0 V; T_j = 25^\circ C$		-	418	-	pF
C_{oss}	output capacitance			-	45	-	pF
C_{rss}	reverse transfer capacitance			-	34	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = -10 V; I_D = -2 A; V_{GS} = -4.5 V; R_{G(ext)} = 6 \Omega; T_j = 25^\circ C$		-	5	-	ns
t_r	rise time			-	14	-	ns
$t_{d(off)}$	turn-off delay time			-	43	-	ns
t_f	fall time			-	16	-	ns
Source-drain diode							
V_{SD}	source-drain voltage	$I_S = -0.8 A; V_{GS} = 0 V; T_j = 25^\circ C$		-	-0.8	-1.2	V



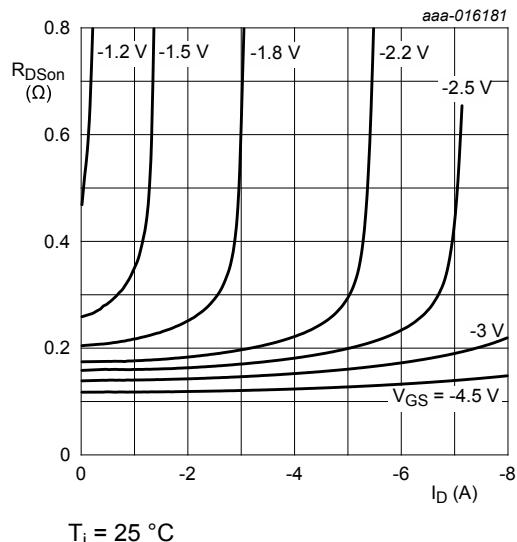
$T_j = 25^\circ\text{C}$

Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values



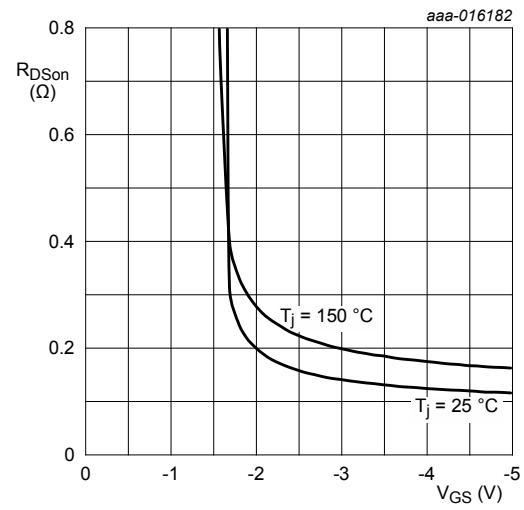
$T_j = 25^\circ\text{C}; V_{DS} = -5\text{ V}$

Fig. 7. Sub-threshold drain current as a function of gate-source voltage



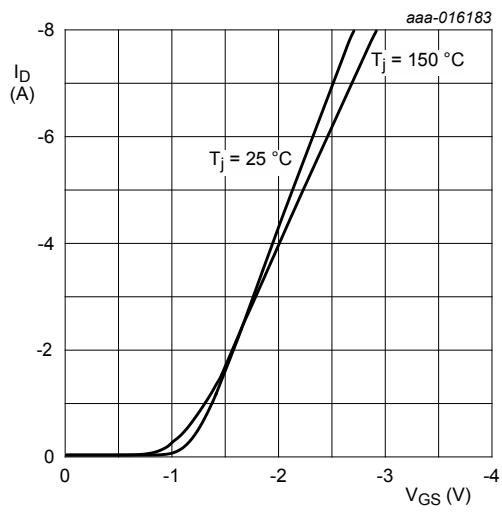
$T_j = 25^\circ\text{C}$

Fig. 8. Drain-source on-state resistance as a function of drain current; typical values



$I_D = -2\text{ A}$

Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values



$$V_{DS} > I_D \times R_{DSon}$$

Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

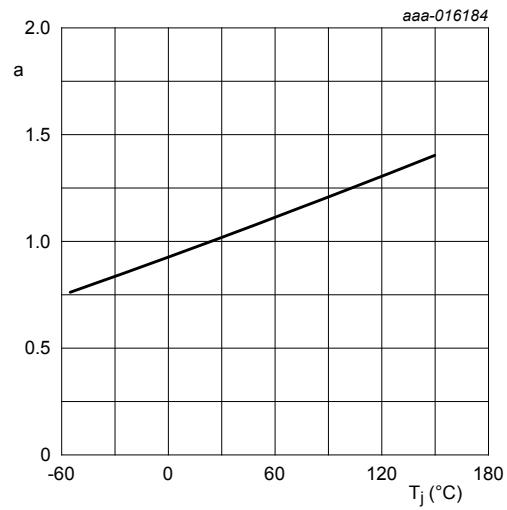
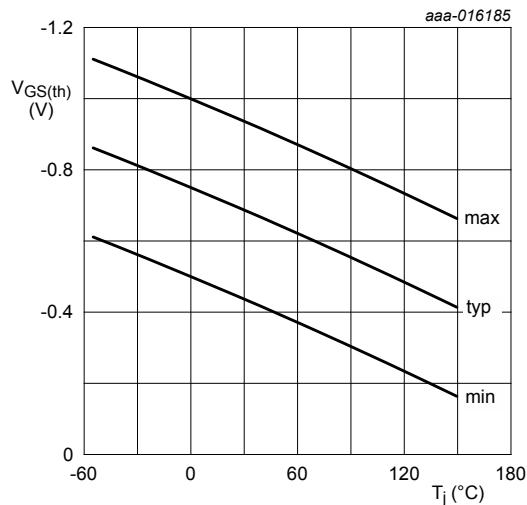


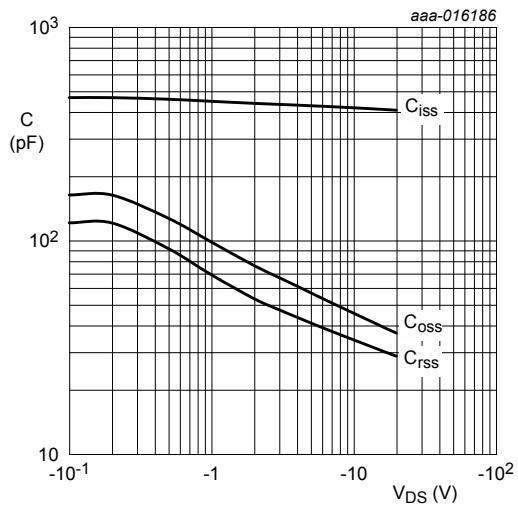
Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

$$a = \frac{R_{DSon}}{R_{DSon}(25^\circ\text{C})}$$



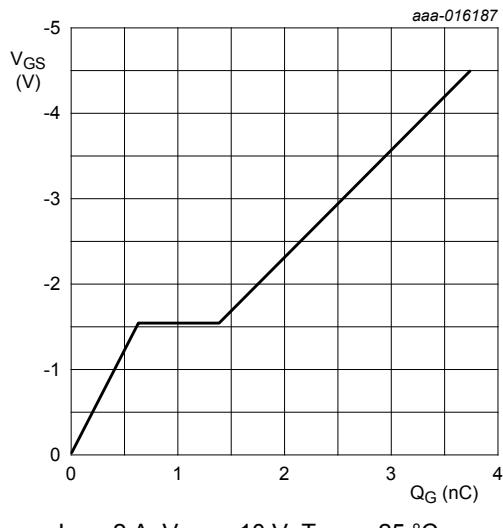
$$I_D = -0.25 \text{ mA}; V_{DS} = V_{GS}$$

Fig. 12. Gate-source threshold voltage as a function of junction temperature



$$f = 1 \text{ MHz}; V_{GS} = 0 \text{ V}$$

Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



$I_D = -2 \text{ A}$; $V_{DS} = -10 \text{ V}$; $T_{amb} = 25^\circ\text{C}$

Fig. 14. Gate-source voltage as a function of gate charge; typical values

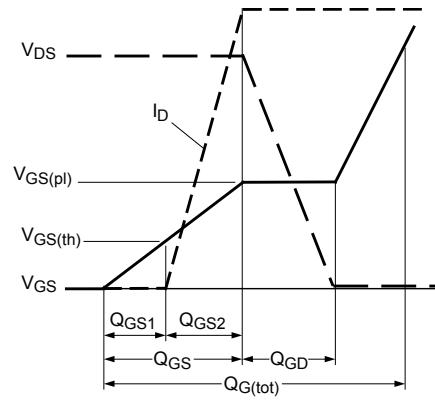
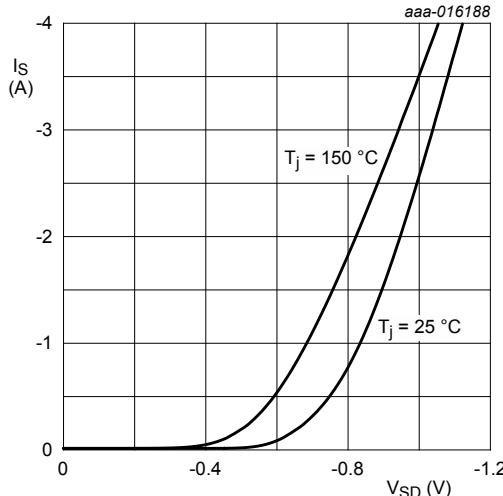


Fig. 15. MOSFET transistor: Gate charge waveform definitions



$V_{GS} = 0 \text{ V}$

Fig. 16. Source current as a function of source-drain voltage; typical values

11. Test information

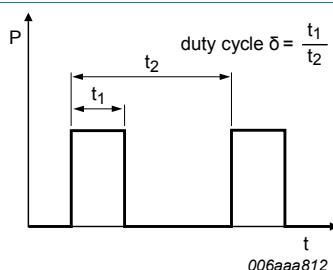


Fig. 17. Duty cycle definition

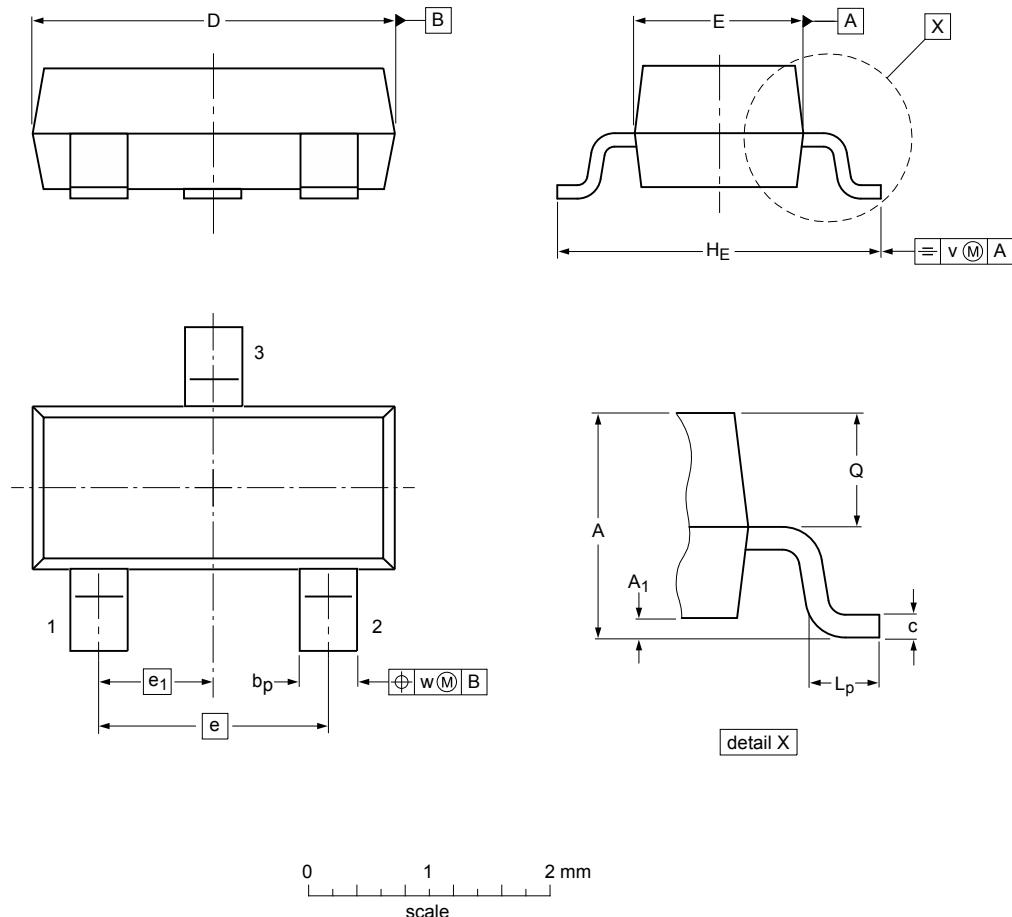
11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline

Plastic surface-mounted package; 3 leads

SOT23



Dimensions (mm are the original dimensions)

Unit	A	A ₁	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	max	1.1	0.1	0.48	0.15	3.0	1.4		2.5	0.45	0.55		
mm	nom							1.9	0.95			0.2	0.1
mm	min	0.9		0.38	0.09	2.8	1.2		2.1	0.15	0.45		

sot23_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT23		TO-236AB				14-06-19 14-09-22

Fig. 18. Package outline TO-236AB (SOT23)

13. Soldering

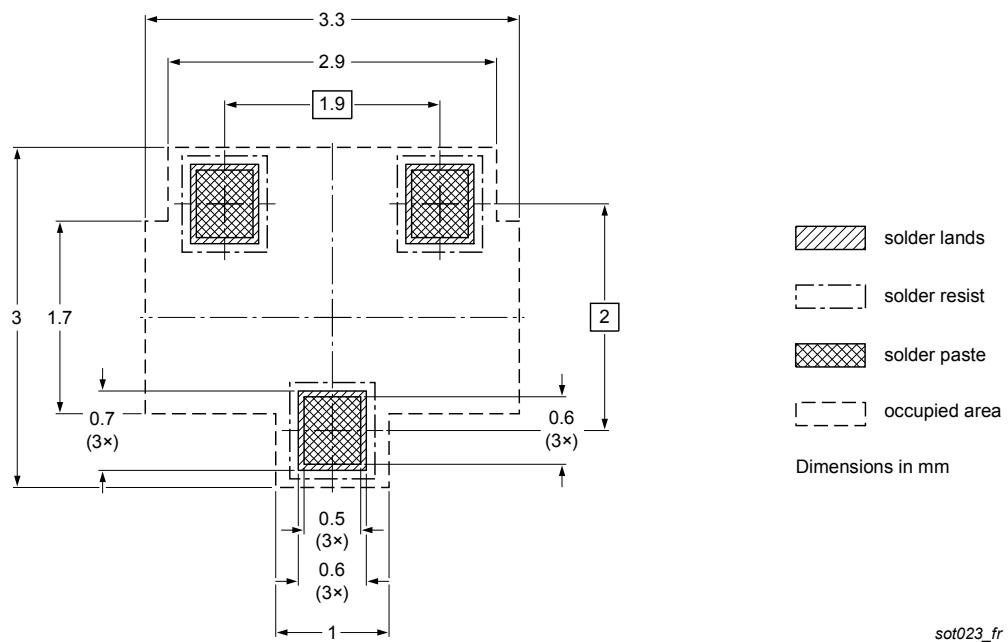


Fig. 19. Reflow soldering footprint for TO-236AB (SOT23)

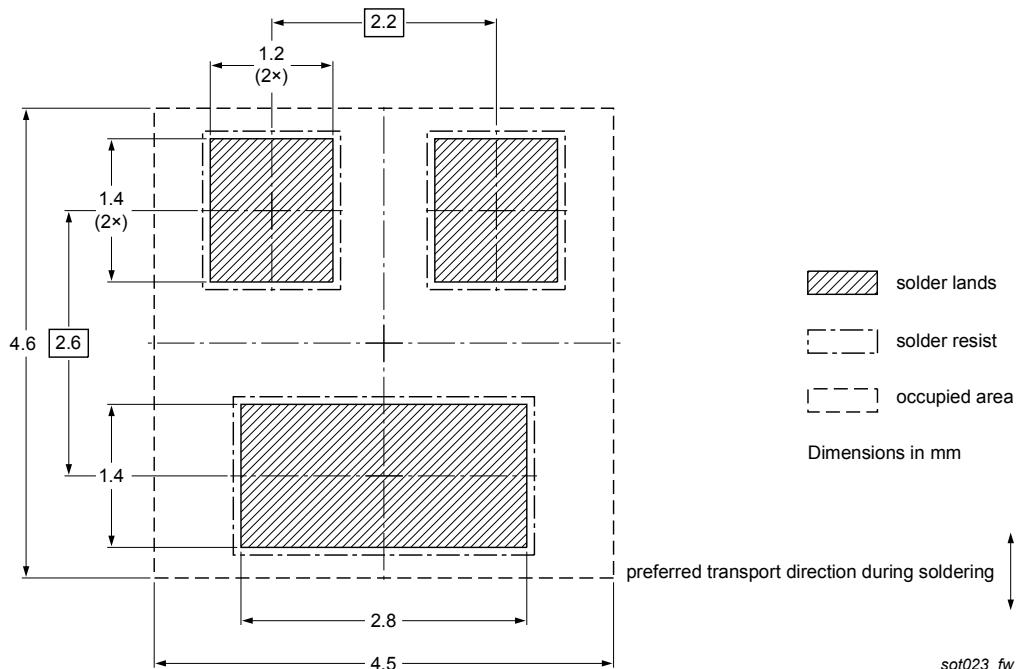


Fig. 20. Wave soldering footprint for TO-236AB (SOT23)

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BSH205G2 v. 2	20150429	Product data sheet	-	BSH205G2 v.1
Modifications:	<ul style="list-style-type: none">• AEC-Q101 qualified			
BSH205G2 v.1	20141215	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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